FAIRCHILD

SEMICONDUCTOR

DM74AS640 **3-STATE Octal Bus Transceiver**

General Description

This advanced Schottky device contains 8 pairs of 3-STATE logic elements configured as octal bus transceiver. This circuit is designed for use in memory, microprocessor systems and in asynchronous bidirectional data buses. This device transmits data from the A bus to the B bus, or vice versa, depending upon the logic level of the direction control input (DIR). The enable input (\overline{G}) can be used to disable the devices, effecting isolation of buses A and B.

The 3-STATE circuitry also contains a protection feature that prevents these transceivers from glitching the bus during power-up or power-down.

October 1986 Revised March 2000

DM74AS640 3-STATE Octal Bus Transceiver

process ■ Functionally and pin for pin compatible with Schottky,

Switching specifications at 50 pF

ture and $V_{\mbox{CC}}$ range

Features

low power Schottky, and advanced low power Schottky TTL counterpart

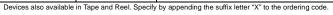
Switching specifications guaranteed over full tempera-

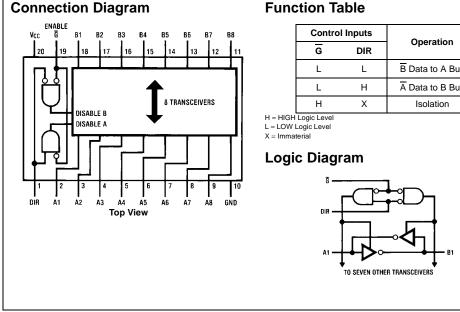
Advanced oxide-isolated, ion-implanted Schottky TTL

- Improved AC performance over Schottky, low power Schottky, and advanced low power Schottky counterparts
- 3-STATE outputs independently controlled on A and B buses
- Low output impedance drive to drive terminated transmission lines to 133Ω
- Specified to interface with CMOS at $V_{OH} = V_{CC} 2V$

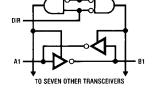
Ordering Code:

Order Number	Package Number	Package Description
DM74AS640WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
DM74AS640N	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide





B Data to A Bus A Data to B Bus



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Absolute Maximum Ratings(Note 1)

Supply Voltage	7V
Input Voltage	
Control Inputs	7V
I/O Ports	5.5V
Operating Free Air Temperature Range	$0^{\circ}C$ to $+70^{\circ}C$
Storage Temperature Range	$-65^{\circ}C$ to $+150^{\circ}C$
Typical θ _{JA}	
N Package	51.5°C
M Package	69.0°C

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Recommended Operating Conditions

Symbol	Parameter	Min	Тур	Max	Units
V _{CC}	Supply Voltage	4.5	5	5.5	V
V _{IH}	HIGH Level Input Voltage	2			V
VIL	LOW Level Input Voltage			0.8	V
I _{OH}	HIGH Level Output Current			-15	mA
I _{OL}	LOW Level Output Current			64	mA
T _A	Free Air Operating Temperature	0		70	°C

Electrical Characteristics

over recommended operating free air temperature range (unless otherwise noted)

Symbol	Parameter	Conditions		Min	Typ (Note 2)	Max	Units
VI	Input Clamp Voltage	$V_{CC} = Min, I_I = -18 \text{ mA}$				-1.2	V
V _{он}	HIGH Level	$V_{CC} = 4.5V$ to 5.5V, $I_{OH} = -2$ mA		V _{CC} – 2			V
	Output Voltage	$V_{CC} = 4.5V, I_{OH} = -3 \text{ mA}$		2.4			V
		$V_{CC} = 4.5V$, $I_{OH} = Max$		2.4			V
V _{OL}	LOW Level Output Voltage	V _{CC} = Min, I _{OL} = Max			0.35	0.55	V
l _l	Input Current at Max	$V_{CC} = Max, V_I = 7V,$				0.1	mA
	Input Voltage	$(V_I = 5.5V \text{ for A or B Ports})$				0.1	mA
IIH	HIGH Level	V _{CC} = Max	Control Inputs			20	μA
	Input Current	V _I = 2.7V (Note 3)	A or B Ports			70	μΑ
IIL	LOW Level	V _{CC} = Max,	Control Inputs			-0.5	mA
	Input Current	V _I = 0.4V (Note 3)	A or B Ports			-0.75	mA
I _O	Output Drive Current	$V_{CC} = Max, V_{O} = 2.25V$	•	-50		-150	mA
I _{ссн}	Supply Current with Outputs HIGH	V _{CC} = Max			37	58	mA
ICCL	Supply Current with Outputs LOW	1			78	123	mA
I _{CCZ}	Supply Current with Outputs	1			51	80	mA
	in 3-STATE				51	00	IIIA

Note 2: All typicals are at $V_{CC} = 5.0V$, $T_A = 25^{\circ}C$.

Note 3: For I/O ports, the parameters I_{IH} and I_{IL} include the OFF-State output current, I_{OZH} and I_{OZL}.

over recom		From	То	V _{CC} = Min to Max,		
Symbol	Parameter	(Input)	(Output)	C _L = 50 pF, F	$R_1 = R_2 = 500\Omega$	Units
				Min	Max	
чLН	Propagation Delay Time	A or B	B or A	2	7	ns
	LOW-to-HIGH Level Output	AUB	BUIA	2	'	115
ΉL	Propagation Delay Time	A or B	B or A	2	6	ns
	HIGH-to-LOW Level Output				_	
ZH	Output Enable Time to	G	A or B	2	8	ns
	HIGH Level Output					
ZL	Output Enable Time to	G	A or B	2	10	ns
	LOW Level Output	-				-
ΉZ	Output Disable Time from	G	A or B	2	8	ns
	HIGH Level Output					
ĽZ	Output Disable Time from	G	A or B	2	13	ns
	LOW Level Output	0		-	10	

DM74AS640

